

1-of-16 Decoder/Demultiplexer with Address Latch

High-Performance Silicon-Gate CMOS

The MC74HC4514 is identical in pinout to the MC14514B metal-gate CMOS device. The device inputs are compatible with standard CMOS outputs, with pullup resistors; they are compatible with LSTTL outputs.

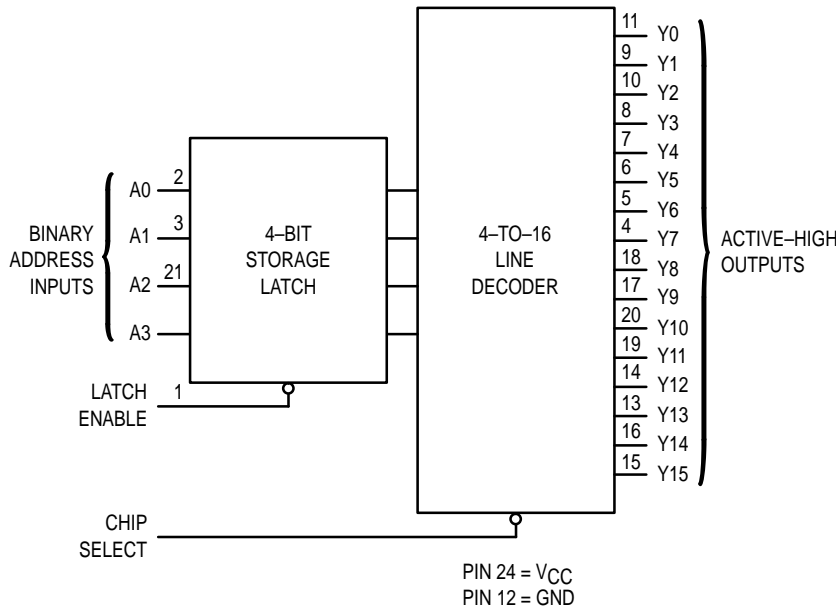
This device consists of a 4-bit storage latch with a Latch Enable and Chip Select input. When a low signal is applied to the Latch Enable input, the Address is stored, and decoded. When the Chip Select input is high, all sixteen outputs are forced to a low level.

The Chip Select input is provided to facilitate the chip-select, demultiplexing, and cascading functions.

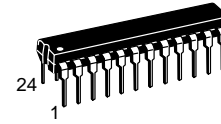
The demultiplexing function is accomplished by using the Address inputs to select the desired device output, and then by using the Chip Select as a data input.

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2 to 6 V
- Low Input Current: 1 μ A
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 268 FETs or 67 Equivalent Gates

LOGIC DIAGRAM



MC74HC4514



N SUFFIX
PLASTIC PACKAGE
CASE 724-03



DW SUFFIX
SOIC PACKAGE
CASE 751E-04

ORDERING INFORMATION

MC74HCXXXXN Plastic
MC74HCXXXXDW SOIC

PIN ASSIGNMENT

LATCH ENABLE	1	24	V _{CC}
A0	2	23	CHIP SELECT
A1	3	22	A3
Y7	4	21	A2
Y6	5	20	Y10
Y5	6	19	Y11
Y4	7	18	Y8
Y3	8	17	Y9
Y1	9	16	Y14
Y2	10	15	Y15
Y0	11	14	Y12
GND	12	13	Y13



MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	- 0.5 to + 7.0	V
V _{in}	DC Input Voltage (Referenced to GND)	- 1.5 to V _{CC} + 1.5	V
V _{out}	DC Output Voltage (Referenced to GND)	- 0.5 to V _{CC} + 0.5	V
I _{in}	DC Input Current, per Pin	± 20	mA
I _{out}	DC Output Current, per Pin	± 25	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins	± 50	mA
P _D	Power Dissipation in Still Air Plastic DIP† SOIC Package†	750 500	mW
T _{stg}	Storage Temperature	- 65 to + 150	°C
T _L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP)	260	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

* Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

† Derating — Plastic DIP: - 10 mW/°C from 65° to 125°C
SOIC Package: - 7 mW/°C from 65° to 125°C

For high frequency or heavy load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	2	6.0	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V _{CC}	V
T _A	Operating Temperature, All Package Types	- 55	+ 125	°C
t _r , t _f	Input Rise and Fall Time (Figure 1) V _{CC} = 2.0 V V _{CC} = 4.5 V V _{CC} = 6.0 V	0	1000 500 400	ns

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V _{CC} V	Guaranteed Limit			Unit				
				- 55 to 25° C	≤ 85° C	≤ 125° C					
V _{IH}	Minimum High-Level Input Voltage	V _{out} = 0.1 V or V _{CC} - 0.1 V I _{out} ≤ 20 μA	2.0	1.5	1.5	1.5	V				
			4.5	3.15	3.15	3.15					
			6.0	4.2	4.2	4.2					
V _{IL}	Maximum Low-Level Input Voltage	V _{out} = 0.1 V or V _{CC} - 0.1 V I _{out} ≤ 20 μA	2.0	0.3	0.3	0.3	V				
			4.5	0.9	0.9	0.9					
			6.0	1.2	1.2	1.2					
V _{OH}	Minimum High-Level Output Voltage	V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA	2.0	1.9	1.9	1.9	V				
			4.5	4.4	4.4	4.4					
			6.0	5.9	5.9	5.9					
V _{OL}	Maximum Low-Level Output Voltage	V _{in} = V _{IH} or V _{IL} I _{out} ≤ 20 μA	2.0	0.1	0.1	0.1	V				
			4.5	0.1	0.1	0.1					
			6.0	0.1	0.1	0.1					
I _{in}	Maximum Input Leakage Current	V _{in} = V _{CC} or GND	6.0	± 0.1	± 1.0	± 1.0	μA				
			I _{CC}	Maximum Quiescent Supply Current (per Package)	V _{in} = V _{CC} or GND I _{out} = 0 μA	6.0		8	80	160	μA
						6.0		8	80	160	

NOTE: Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

AC ELECTRICAL CHARACTERISTICS ($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

Symbol	Parameter	VCC V	Guaranteed Limit			Unit
			- 55 to 25°C	≤ 85°C	≤ 125°C	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, Chip Select to Output Y (Figures 1 and 5)	2.0	175	220	265	ns
		4.5	35	44	53	
		6.0	30	37	45	
t _{PLH}	Maximum Propagation Delay, Input A to Output Y (Figures 2 and 5)	2.0	230	290	345	ns
		4.5	46	58	69	
		6.0	39	49	59	
t _{PHL}		2.0	175	220	265	
		4.5	35	44	53	
		6.0	30	37	45	
t _{PLH}	Maximum Propagation Delay, Latch Enable to Output Y (Figures 3 and 5)	2.0	230	290	345	ns
		4.5	46	58	69	
		6.0	39	49	59	
t _{PHL}		2.0	175	220	265	
		4.5	35	44	53	
		6.0	30	37	45	
t _{TLH} , t _{THL}	Maximum Output Transition Time, Any Output (Figures 1 and 5)	2.0	75	95	110	ns
		4.5	15	19	22	
		6.0	13	16	19	
C _{in}	Maximum Input Capacitance	—	10	10	10	pF

NOTES:

- For propagation delays with loads other than 50 pF, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).
- Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

C _{PD}	Power Dissipation Capacitance (Per Package)*	Typical @ 25°C, VCC = 5.0 V			pF
		70			

* Used to determine the no-load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$. For load considerations, see Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

TIMING REQUIREMENTS (Input $t_r = t_f = 6$ ns)

Symbol	Parameter	VCC V	Guaranteed Limit			Unit
			- 55 to 25°C	≤ 85°C	≤ 125°C	
t _{su}	Minimum Setup Time, Input A to Latch Enable (Figure 4)	2.0	100	125	150	ns
		4.5	20	25	30	
		6.0	17	21	26	
t _h	Minimum Hold Time, Latch Enable to Input A (Figure 4)	2.0	5	5	5	ns
		4.5	5	5	5	
		6.0	5	5	5	
t _w	Minimum Pulse Width, Latch Enable (Figure 3)	2.0	80	100	120	ns
		4.5	16	20	24	
		6.0	14	17	20	
t _r , t _f	Maximum Input Rise and Fall Times (Figure 1)	2.0	1000	1000	1000	ns
		4.5	500	500	500	
		6.0	400	400	400	

NOTE: Information on typical parametric values can be found in Chapter 2 of the Motorola High-Speed CMOS Data Book (DL129/D).

SWITCHING WAVEFORMS

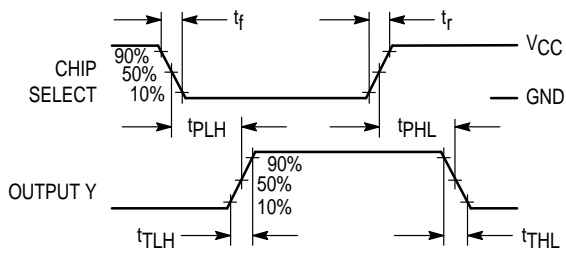


Figure 1.

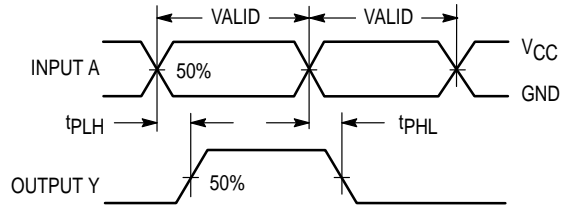


Figure 2.

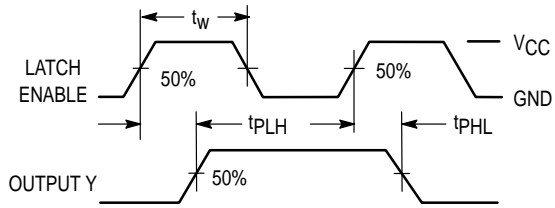


Figure 3.

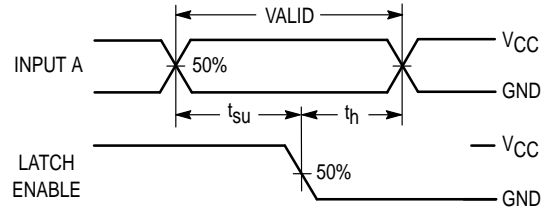
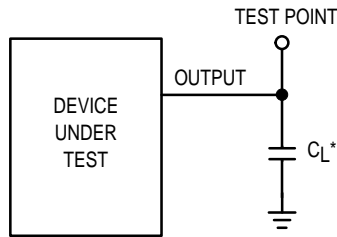


Figure 4.



* Includes all probe and jig capacitance

Figure 5. Test Circuit

FUNCTION TABLE

Latch Enable	Chip Select	Address Inputs				Selected Output (High)
		A3	A2	A1	A0	
H	L	L	L	L	L	Y0
H	L	L	L	L	H	Y1
H	L	L	L	H	L	Y2
H	L	L	L	H	H	Y3
H	L	L	H	L	L	Y4
H	L	L	H	L	H	Y5
H	L	L	H	H	L	Y6
H	L	L	H	H	H	Y7
H	L	H	L	L	L	Y8
H	L	H	L	L	H	Y9
H	L	H	L	H	L	Y10
H	L	H	L	H	H	Y11
H	L	H	H	L	L	Y12
H	L	H	H	L	H	Y13
H	L	H	H	H	L	Y14
H	L	H	H	H	H	Y15
X	H	X	X	X	X	All Outputs = L
L	L	X	X	X	X	Latched Data

PIN DESCRIPTIONS

ADDRESS INPUTS

A0, A1, A2, A3 (Pins 2, 3, 21, 22)

Address Inputs. These inputs are decoded to produce a high level on one of 16 outputs. The inputs are arranged such that A3 is the most-significant bit and A0 is the least-significant bit. The decimal equivalent of the binary input address indicates which of the 16 data outputs, Y0–Y15, is selected.

OUTPUTS

Y0 – Y15 (Pins 11, 9, 10, 8, 7, 6, 5, 4, 18, 17, 20, 19, 14, 13, 16, 15)

Active-High Outputs. These outputs produce a high level when selected (Latch Enable = H, Chip Select = L) and are at a low level when not selected.

CONTROL INPUTS

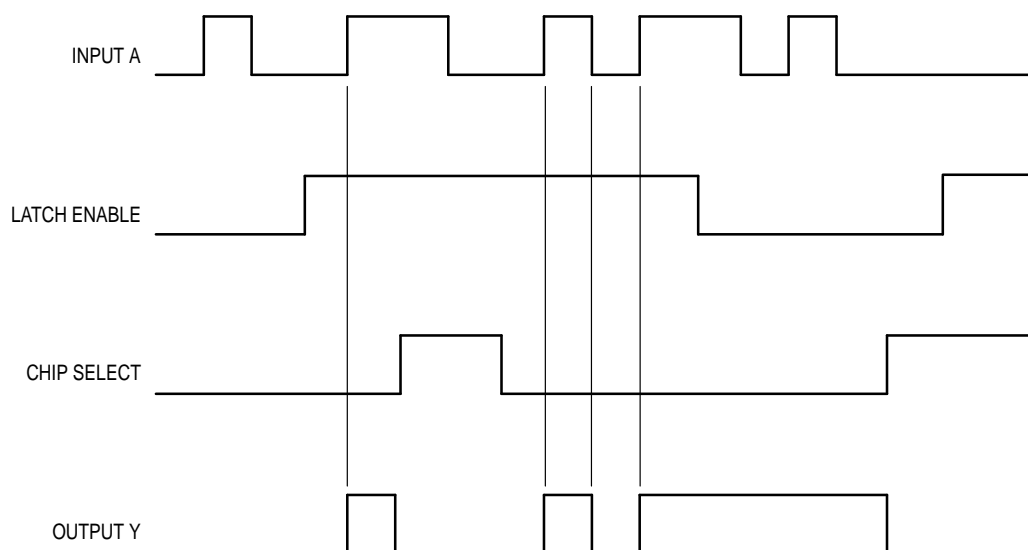
Latch Enable (Pin 1)

Latch Enable Input. A low level on this input stores the data on the Address data inputs in the 4-bit latch. A high level on the Latch Enable input makes the latch transparent and allows the outputs to follow the inputs. Note that the data is latched only while the Latch Enable input is at a low level.

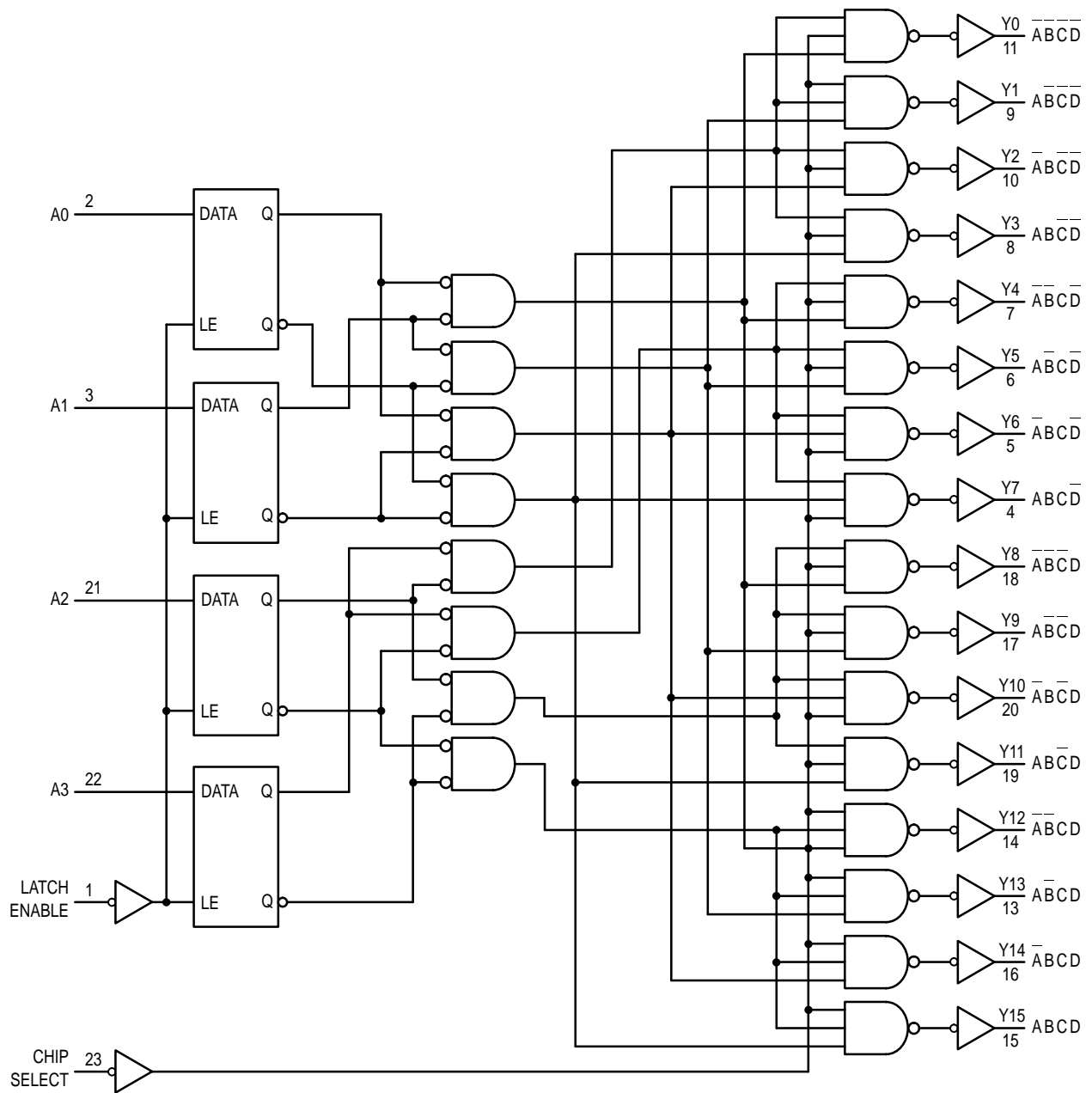
Chip Select (Pin 23)

Chip Select Input. A high on this input produces a low level on all outputs, regardless of what appears at the address or Latch Enable inputs. A low level on the Chip Select input allows the selected output to produce a high level.

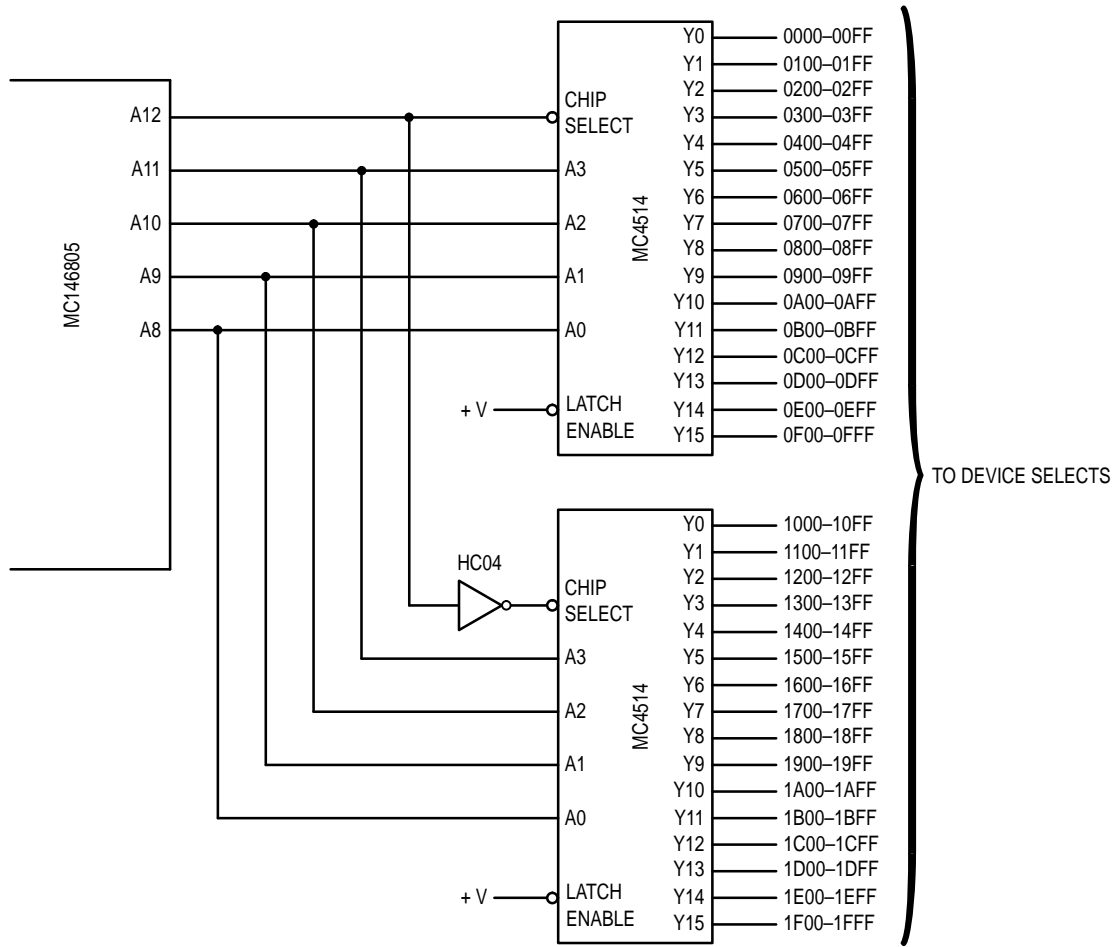
TIMING DIAGRAM



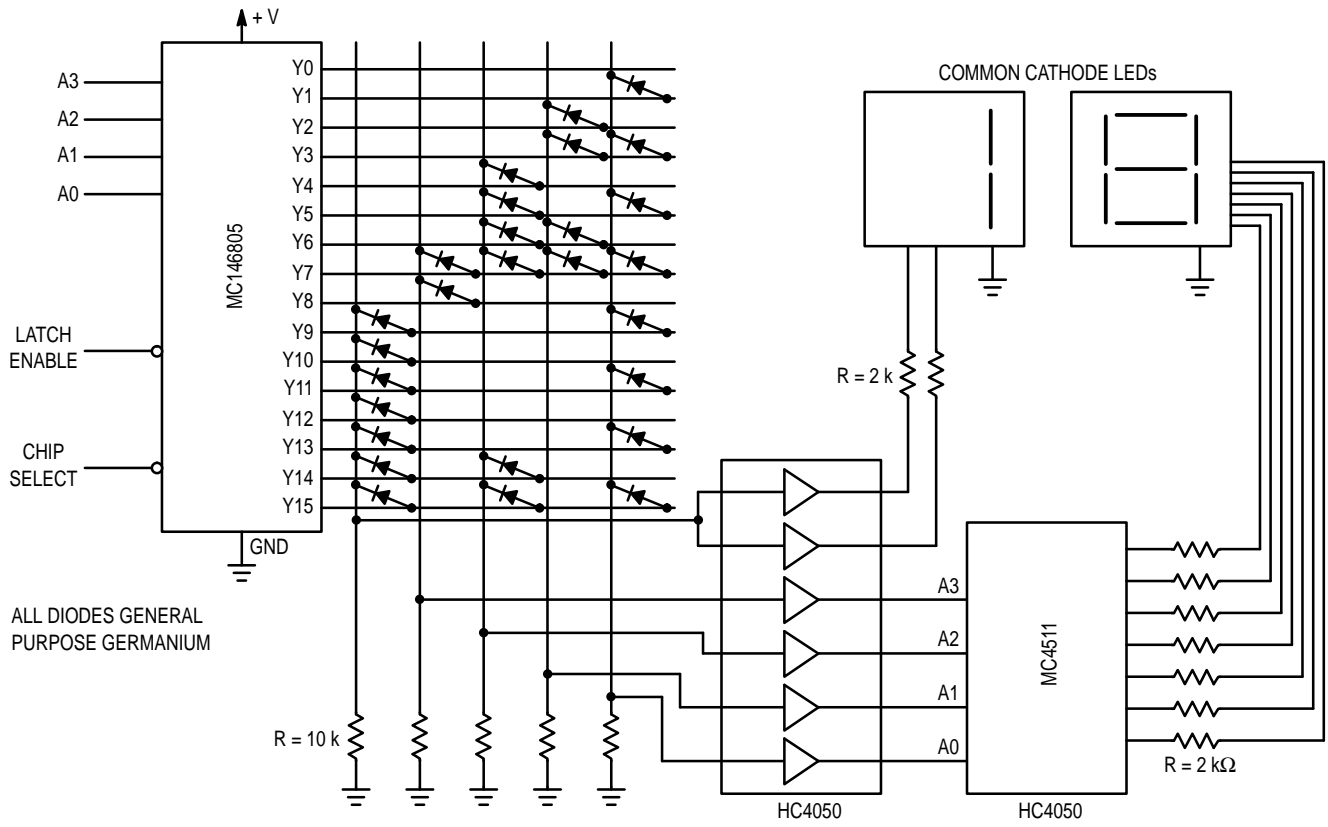
EXPANDED LOGIC DIAGRAM



MICROPROCESSOR MEMORY DECODING

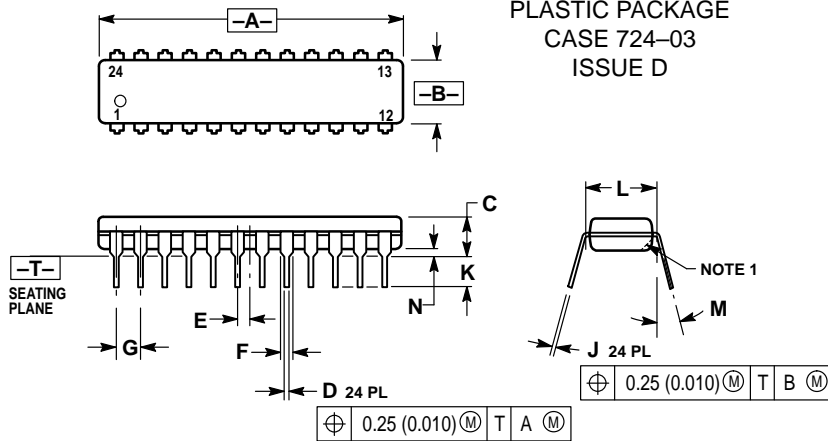


CODE TO CODE CONVERSION — HEXADECIMAL TO BCD



OUTLINE DIMENSIONS

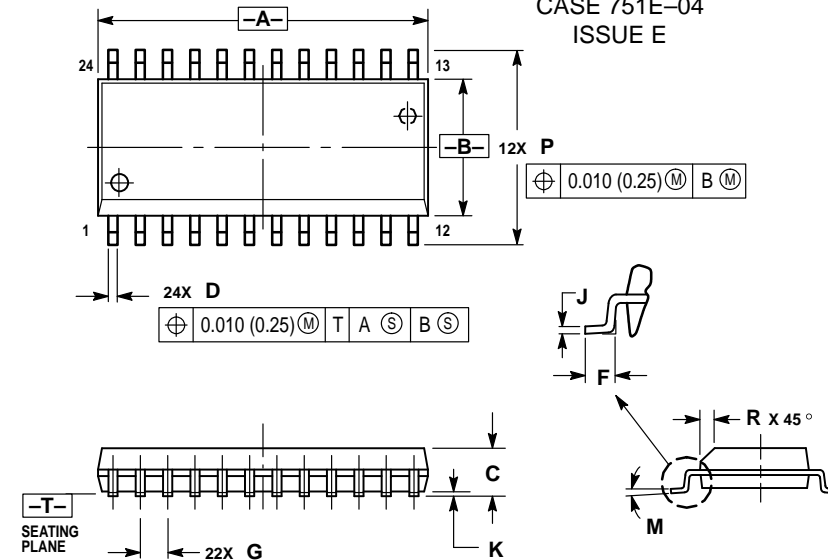
N SUFFIX
PLASTIC PACKAGE
CASE 724-03
ISSUE D



- NOTES:
1. CHAMFERED CONTOUR OPTIONAL.
 2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 4. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.230	1.265	31.25	32.13
B	0.250	0.270	6.35	6.85
C	0.145	0.175	3.69	4.44
D	0.015	0.020	0.38	0.51
E	0.050 BSC		1.27 BSC	
F	0.040	0.060	1.02	1.52
G	0.100 BSC		2.54 BSC	
J	0.007	0.012	0.18	0.30
K	0.110	0.140	2.80	3.55
L	0.300 BSC		7.62 BSC	
M	0°	15°	0°	15°
N	0.020	0.040	0.51	1.01

DW SUFFIX
PLASTIC SOIC PACKAGE
CASE 751E-04
ISSUE E



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	15.25	15.54	0.601	0.612
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.41	0.90	0.016	0.035
G	1.27 BSC		0.050 BSC	
J	0.23	0.32	0.009	0.013
K	0.13	0.29	0.005	0.011
M	0°	8°	0°	8°
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

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